

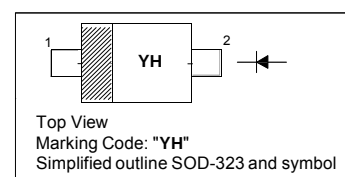
SURFACE MOUNT SCHOTTKY BARRIER DIODE

Features

- Low forward voltage drop

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Absolute Maximum Ratings ($T_a = 25\text{ }^{\circ}\text{C}$)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	30	V
Non-Repetitive Peak Reverse Voltage	V_{RSM}	30	V
DC Blocking Voltage	V_R	30	V
Forward Continuous Current	I_{FM}	100	mA
Non-Repetitive Peak Forward Surge Current ($t \leq 10\text{ ms}$)	I_{FSM}	750	mA
Power Dissipation	P_d	250	mW
Operating and Storage Temperature Range	T_j, T_{stg}	- 65 to + 125	$^{\circ}\text{C}$

Characteristics at $T_a = 25\text{ }^{\circ}\text{C}$

Parameter	Symbol	Min.	Max.	Unit
Forward Voltage at $I_F = 50\text{ mA}$ at $I_F = 100\text{ mA}$	V_F	- -	0.55 0.8	V
Reverse Breakdown Voltage at $I_R = 100\text{ }\mu\text{A}$	$V_{(BR)R}$	30	-	V
Reverse Current at $V_R = 25\text{ V}$	I_R	-	1	μA

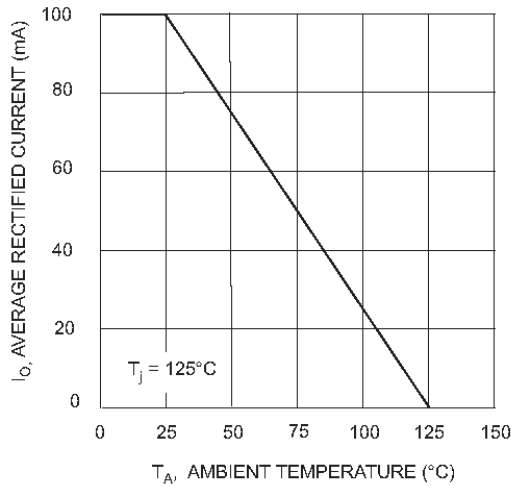


Fig. 1 Forward Current Derating Curve

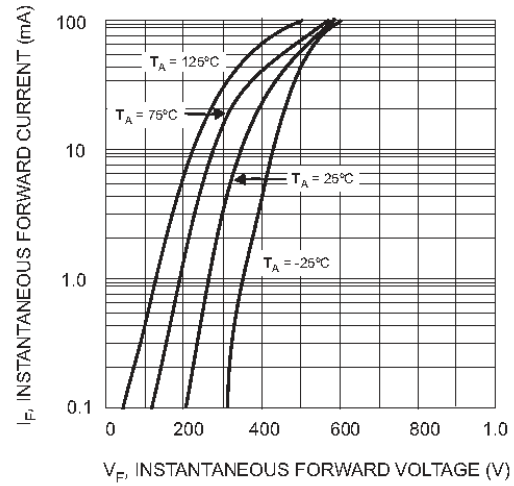


Fig. 2 Typical Forward Characteristics

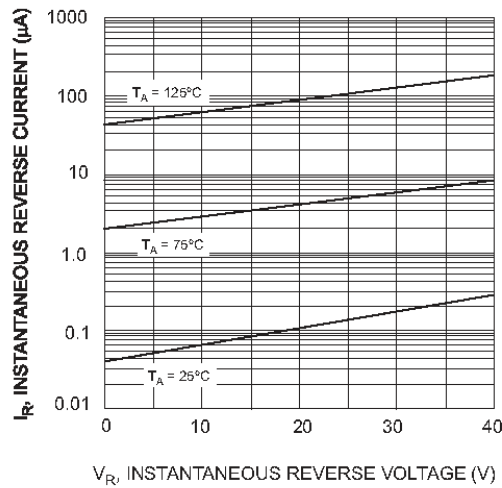


Fig. 3 Typical Reverse Characteristics

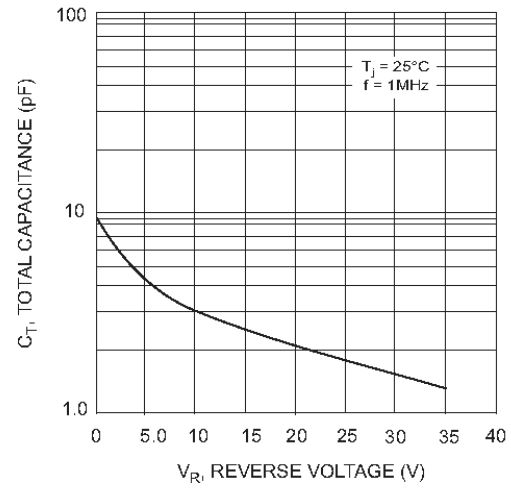


Fig. 4 Total Capacitance vs. Reverse Voltage